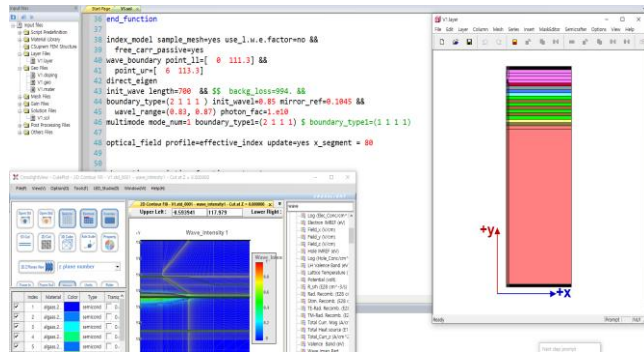
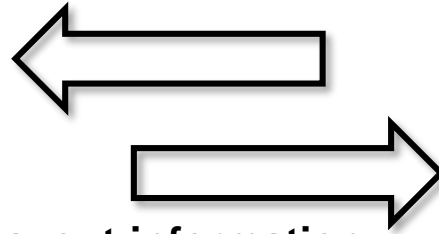


Yonsei Univ. & QSI



Yonsei University

Fabrication



Layout information



QSI

1 W, 850 nm
Laser Diode

Yonsei University (LD simulation)

- Key parameter extraction
=> Contact resistance, internal loss, non-radiative recomb., etc.
- LD design optimization

QSI

- Measurement & Fabrication

LD Team's Research

